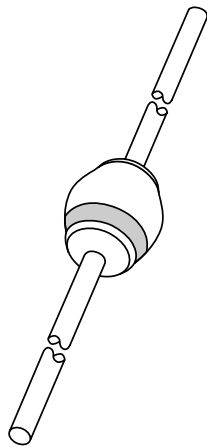


DATA SHEET



BYM99

**Ultra fast low-loss
controlled avalanche rectifier**

Product specification
Supersedes data of June 1994
File under Discrete Semiconductors, SC01

1996 Feb 19

Ultra fast low-loss controlled avalanche rectifier

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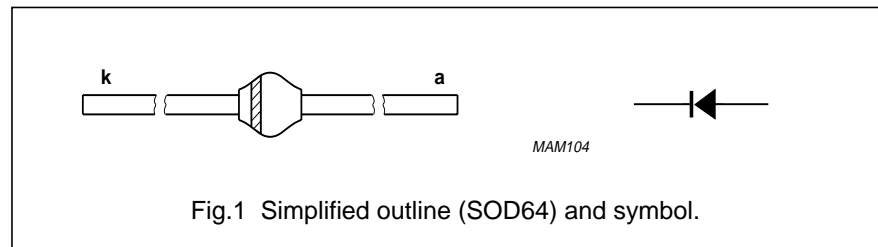
FEATURES

- Glass passivated
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack
- Also available with preformed leads for easy insertion.

DESCRIPTION

Rugged glass SOD64 package, using a high temperature alloyed construction.

This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage		–	600	V
V_R	continuous reverse voltage		–	600	V
$I_{F(AV)}$	average forward current	$T_{tp} = 50\text{ °C}$; lead length = 10 mm see Fig. 2; averaged over any 20 ms period; see also Fig 6	–	1.8	A
		$T_{amb} = 60\text{ °C}$; PCB mounting (see Fig.10); see Fig. 3; averaged over any 20 ms period; see also Fig. 6	–	0.8	A
I_{FRM}	repetitive peak forward current	$T_{tp} = 50\text{ °C}$; see Fig. 4	–	15	A
		$T_{amb} = 60\text{ °C}$; see Fig. 5	–	7	A
I_{FSM}	non-repetitive peak forward current	$t = 10\text{ ms}$ half sine wave; $T_j = T_{jmax}$ prior to surge; $V_R = V_{RRMmax}$	–	40	A
E_{RSM}	non-repetitive peak reverse avalanche energy	$L = 120\text{ mH}$; $T_j = T_{jmax}$ prior to surge; inductive load switched off	–	10	mJ
T_{stg}	storage temperature		–65	+175	°C
T_j	junction temperature		–65	+150	°C

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ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	forward voltage	$I_F = 3\text{ A}$; $T_j = T_{j\text{ max}}$; see Fig. 7	–	–	1.95	V
		$I_F = 3\text{ A}$; see Fig. 7	–	–	3.60	V
$V_{(BR)R}$	reverse avalanche breakdown voltage	$I_R = 0.1\text{ mA}$	700	–	–	V
I_R	reverse current	$V_R = V_{RRM\text{ max}}$; see Fig. 8	–	–	5	μA
		$V_R = V_{RRM\text{ max}}$; $T_j = 150\text{ °C}$; see Fig. 8	–	–	75	μA
t_{rr}	reverse recovery time	when switched from $I_F = 0.5\text{ A}$ to $I_R = 1\text{ A}$; measured at $I_R = 0.25\text{ A}$; see Fig. 12	–	–	15	ns
C_d	diode capacitance	$f = 1\text{ MHz}$; $V_R = 0\text{ V}$; see Fig. 9	–	135	–	pF
$\left \frac{dI_R}{dt} \right $	maximum slope of reverse recovery current	when switched from $I_F = 1\text{ A}$ to $V_R \geq 30\text{ V}$ and $dI_F/dt = -1\text{ A}/\mu\text{s}$; see Fig.11	–	–	3	$\text{A}/\mu\text{s}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-tp}}$	thermal resistance from junction to tie-point	lead length = 10 mm	25	K/W
$R_{th\ j\text{-a}}$	thermal resistance from junction to ambient	note 1	75	K/W

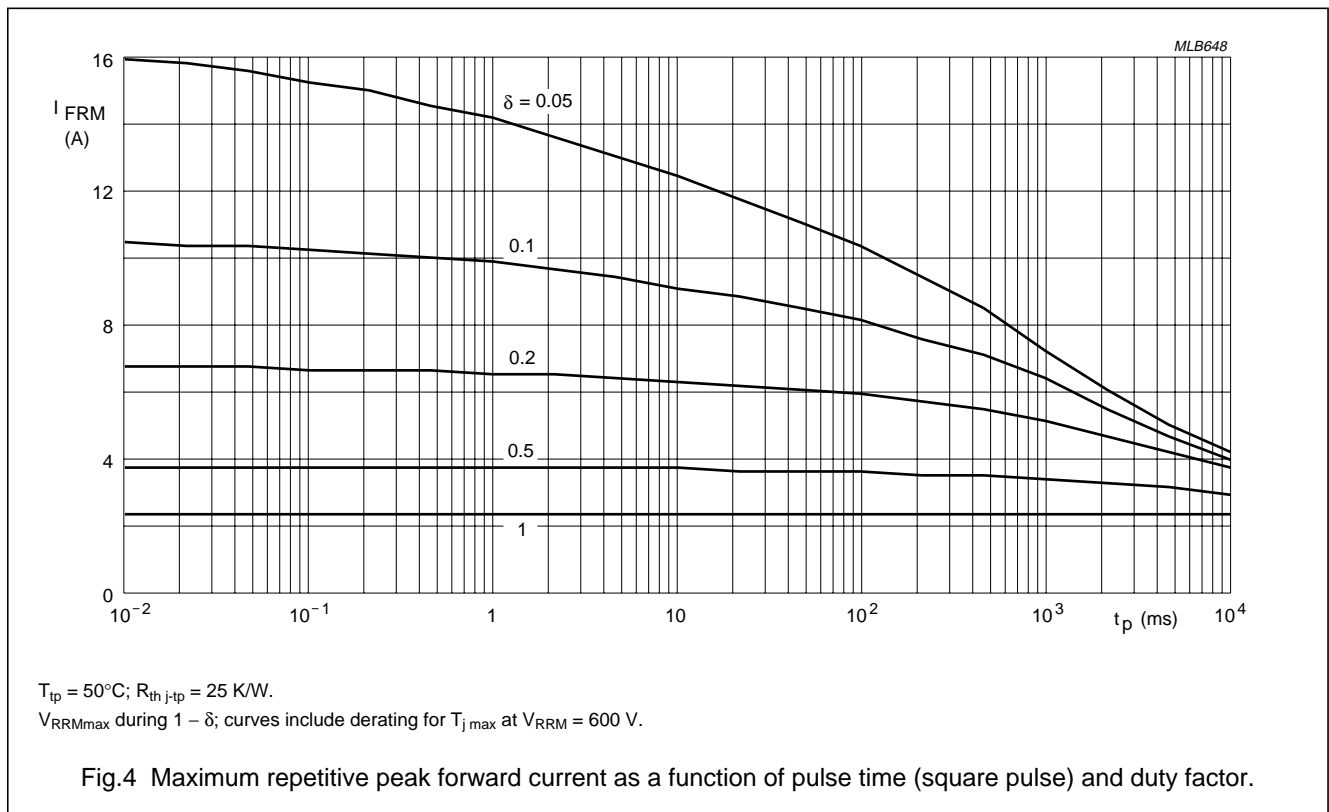
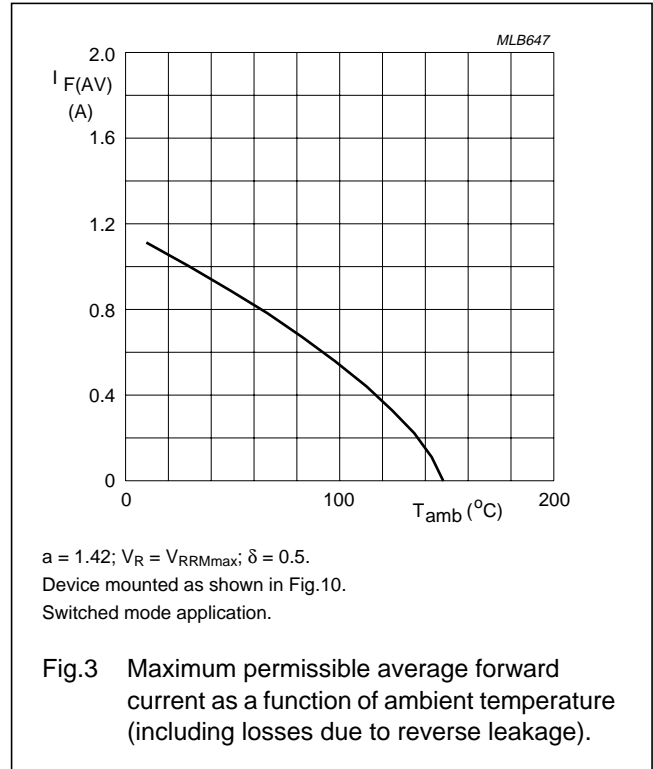
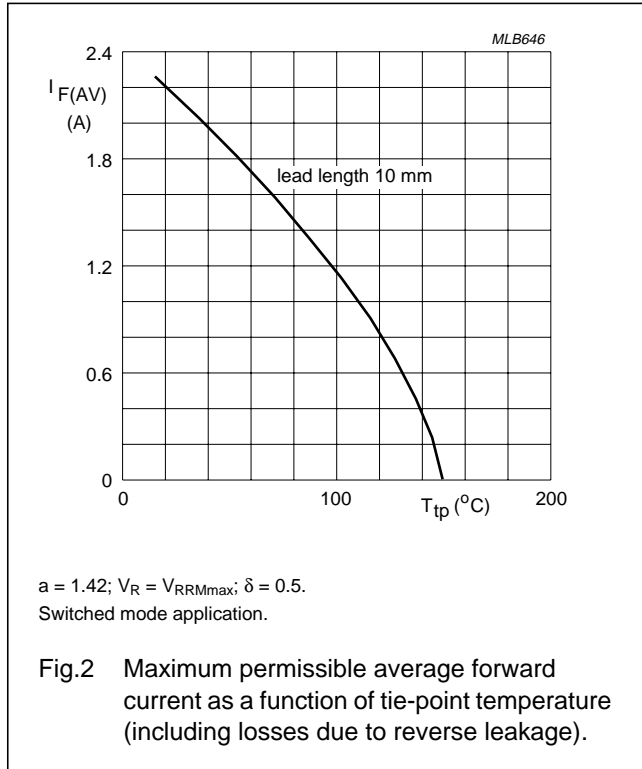
Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer $\geq 40\ \mu\text{m}$, see Fig.10. For more information please refer to the 'General Part of Handbook SC01'.

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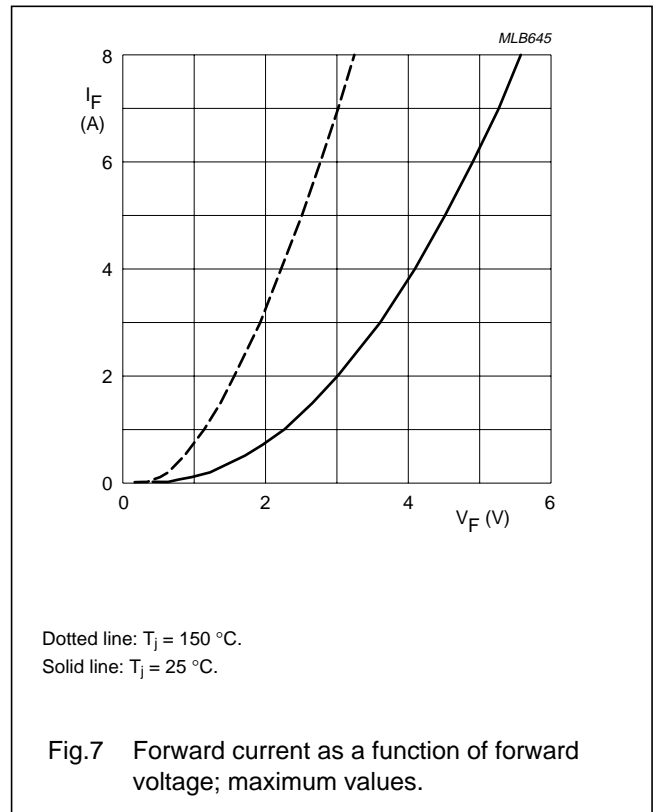
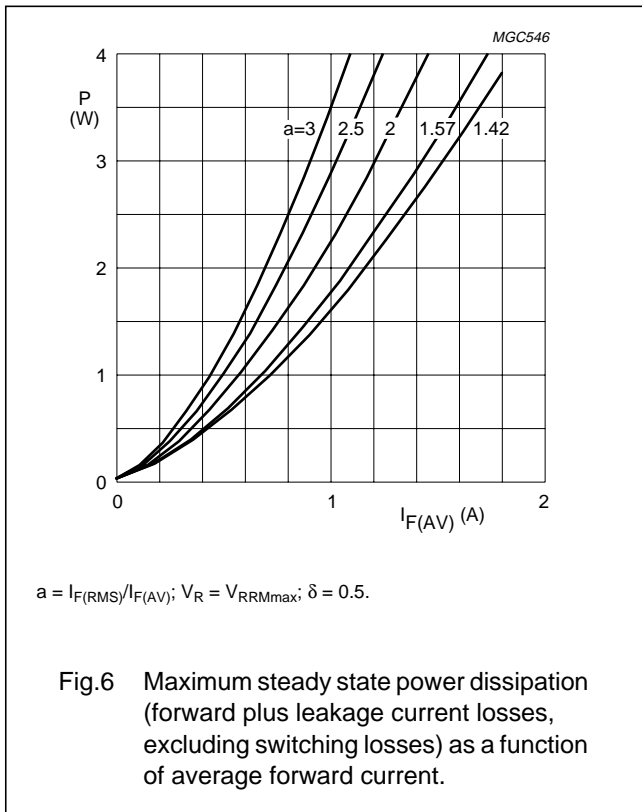
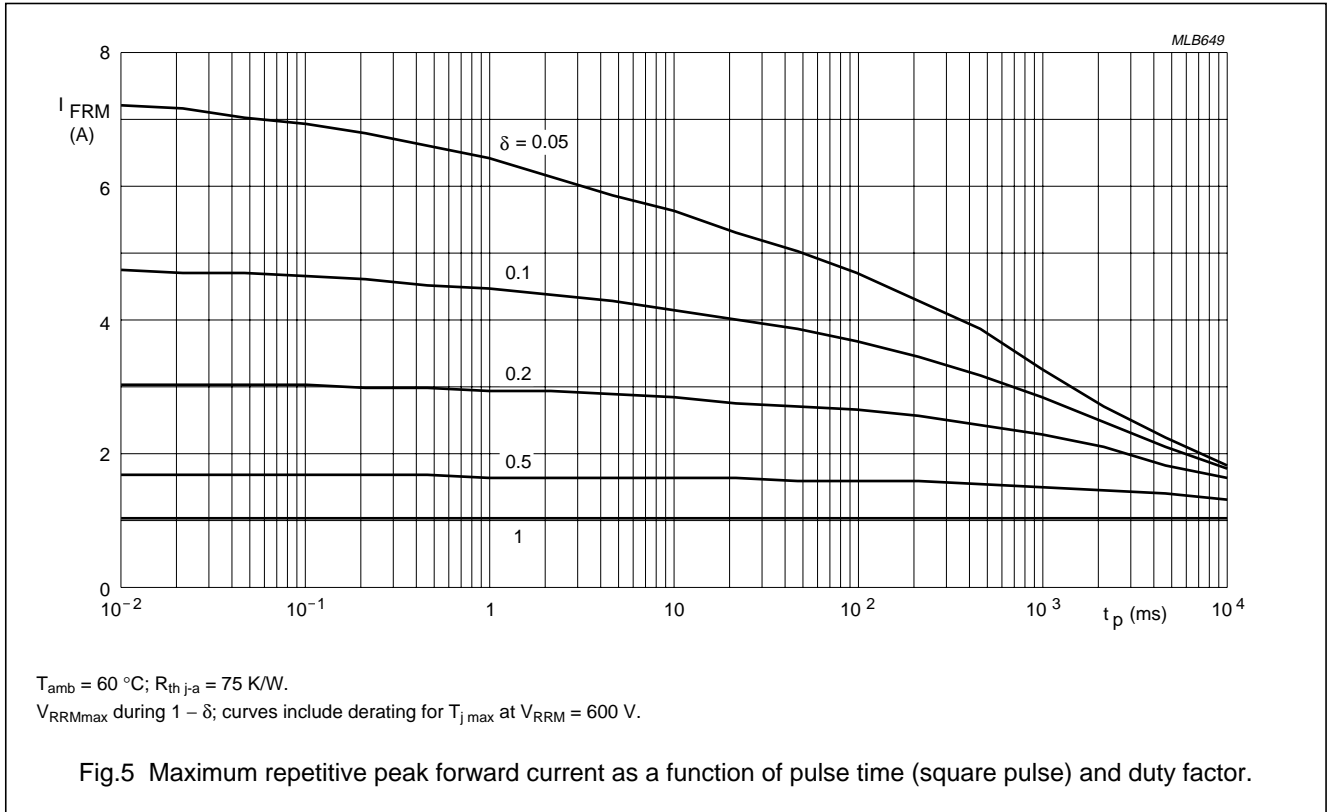
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GRAPHICAL DATA



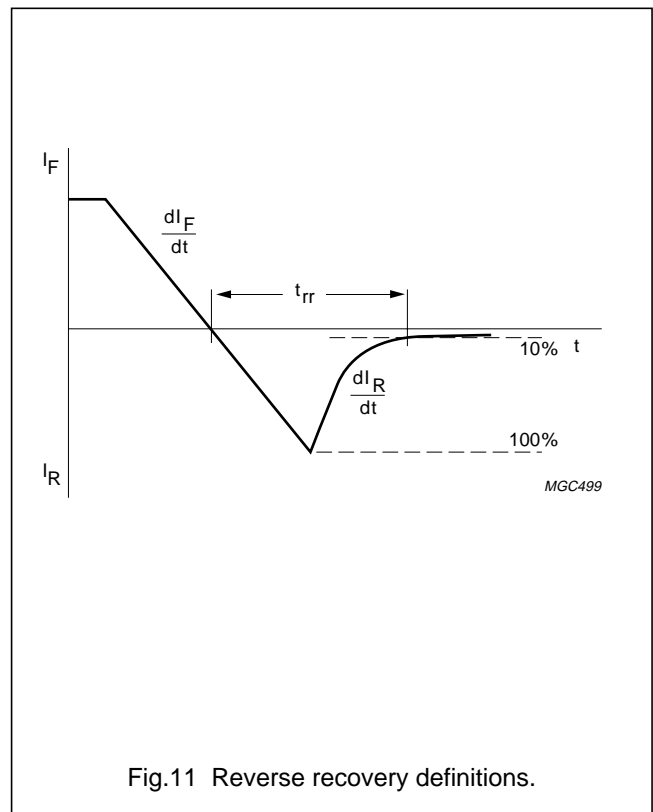
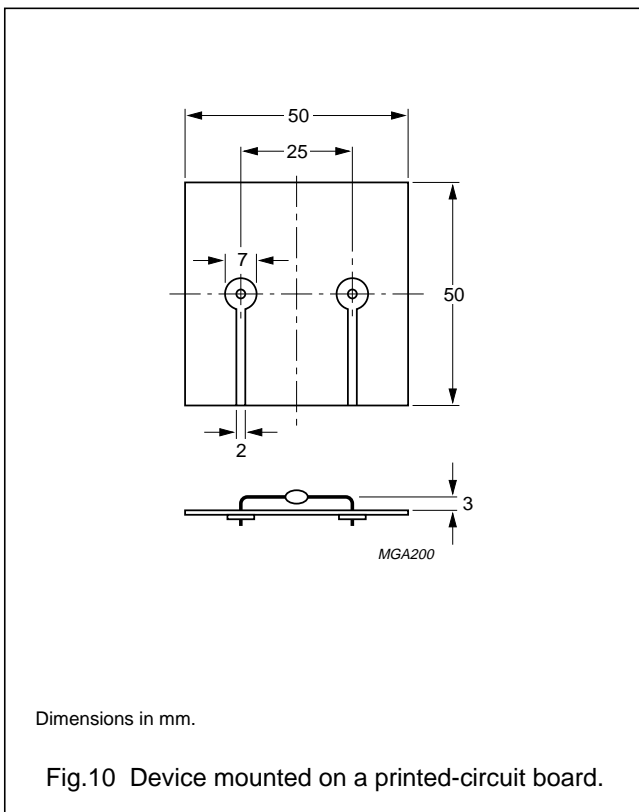
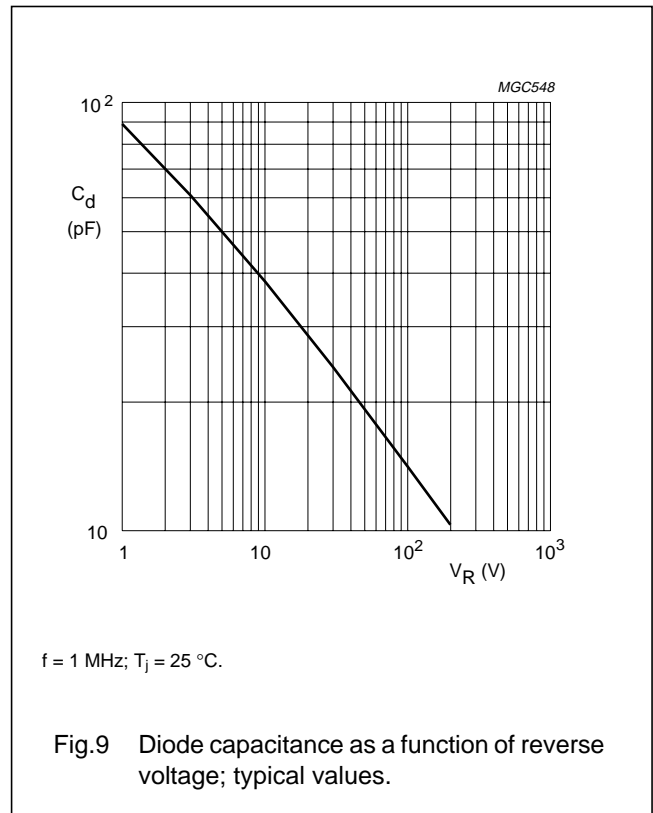
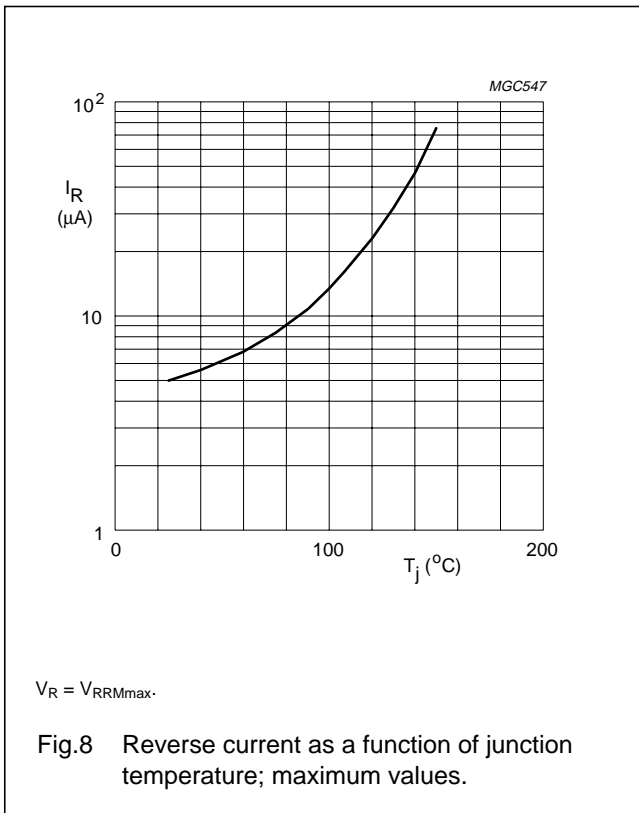
Ultra fast low-loss controlled avalanche rectifier

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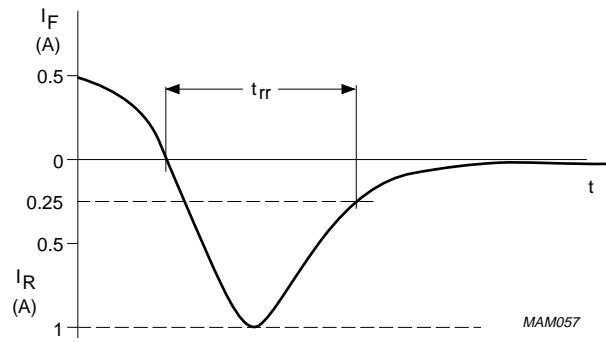
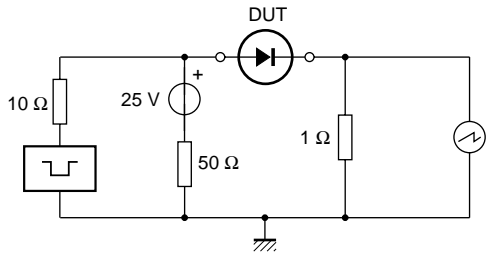
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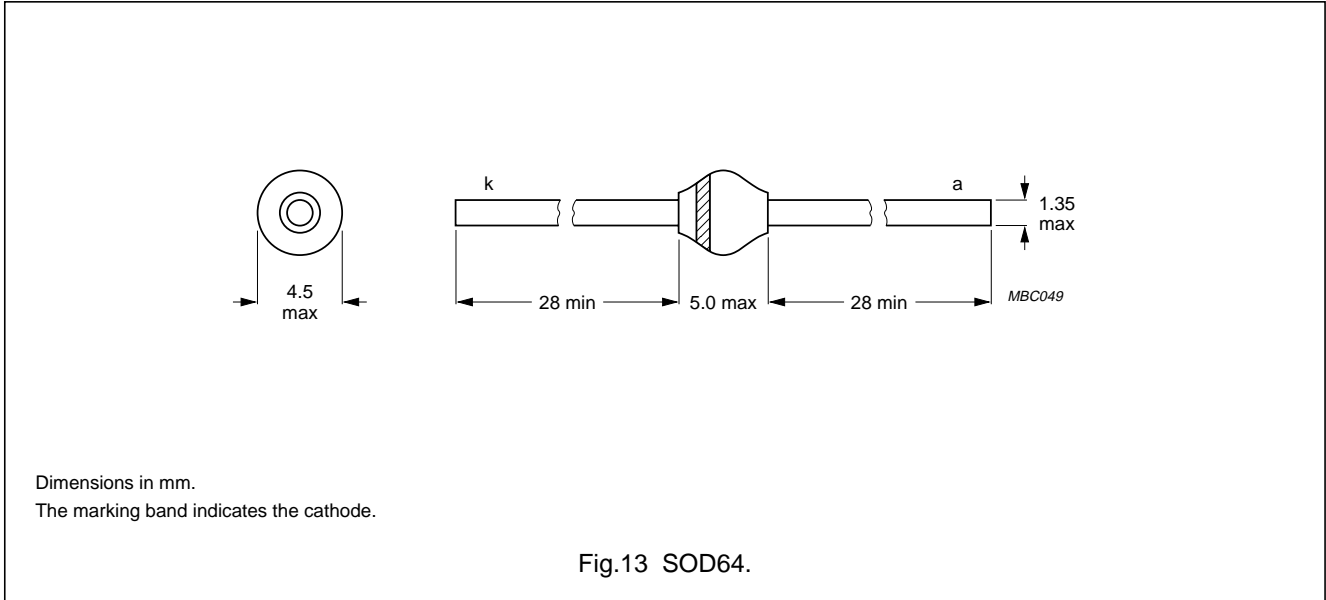
Input impedance oscilloscope: 1 MΩ, 22 pF; $t_r \leq 7$ ns.
Source impedance: 50 Ω; $t_r \leq 15$ ns.

Fig.12 Test circuit and reverse recovery time waveform and definition.

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PACKAGE OUTLINE



DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.